

# DCR370T18

# **Phase Control Thyristor**

DS6024-2 June 2019 (LN38843)

### FEATURES

- Double Side Cooling
- High Surge Capability

### **KEY PARAMETERS**

	1800 V
I <sub>T(AV)</sub>	370 A
ITSM	5000 A
dV/dt*	1000 V/µs
dl/dt	200 A/µs

#### \* Higher dV/dt selections available

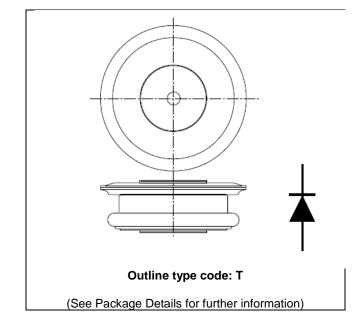


Fig. 1 Package outline

### **APPLICATIONS**

- High Power Drives
- High Voltage Power Supplies
- Static Switches

#### **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages V <sub>DRM</sub> and V <sub>RRM</sub> V	Conditions
DCR370T18 DCR370T16 DCR370T14 DCR370T12	1800 1600 1400 1200	$\begin{array}{l} T_{vj} = -40^{\circ}C \ to \ 125^{\circ}C, \\ I_{DRM} = I_{RRM} = 30mA, \\ V_{DRM}, \ V_{RRM} \ t_p = 10ms, \\ V_{DSM} \& \ V_{RSM} = \\ V_{DRM} \& \ V_{RRM} \ +100V \\ respectively \end{array}$

Lower voltage grades available.

### **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

#### DCR370T18

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.



#### **CURRENT RATINGS**

T<sub>case</sub> = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
I <sub>T(AV)</sub>	Mean on-state current	Half wave resistive load	370	А
I <sub>T(RMS)</sub>	RMS value	-	580	А
Ι <sub>Τ</sub>	Continuous (direct) on-state current	-	520	А

### SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I <sub>TSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 125^{\circ}C$	5.0	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 0	0.125	MA <sup>2</sup> s

## THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	5	Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance – junction to case	Double side cooled	DC	-	0.08	°C/W
R <sub>th(c-h)</sub>	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.02	°C/W
T <sub>vj</sub>	Virtual junction temperature	Blocking V <sub>DRM</sub> / <sub>VRRM</sub>		-	125	°C
T <sub>stg</sub>	Storage temperature range			-40	140	°C
Fm	Clamping force			4	6	kN

## **DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Test Conditio	ons	Min.	Max.	Units
I <sub>RRM</sub> /I <sub>DRM</sub>	Peak reverse and off-state current	At V <sub>RRM</sub> /V <sub>DRM</sub> , T <sub>case</sub> = 125°C	At V <sub>RRM</sub> /V <sub>DRM</sub> , T <sub>case</sub> = 125°C		30	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V <sub>DRM</sub> , T <sub>j</sub> = 125°C, ga	ate open	1000	-	V/µs
dl/dt	Rate of rise of on-state current	From 67% V <sub>DRM</sub> to 1000A	Repetitive 50Hz	-	200	A/µs
		Gate source 30V, $10\Omega$ ,	Non-repetitive	-	1000	A/µs
		t <sub>r</sub> < 0.5µs, T <sub>j</sub> = 125°C				
VT	On-state voltage	IT = 600A, T <sub>case</sub> = 125°C			1.62	V
V <sub>T(TO)</sub>	Threshold voltage – Low level	T <sub>case</sub> = 125°C		-	0.93	V
r <sub>T</sub>	On-state slope resistance – Low level	T <sub>case</sub> = 125°C		-	1.15	mΩ
t <sub>gd</sub>	Delay time	$V_D = 67\% V_{DRM}$ , gate source	30V, 10Ω	-	3.0	μs
		$t_r = 0.5 \mu s, T_j = 25^{\circ}C$				
tq	Turn-off time	$T_j = 125^{\circ}C, V_R = 100V, dl/dt$	= 10A/µs,	-	150	μs
		$dV_{DR}/dt = 20V/\mu s$ linear to 67	7% V <sub>DRM</sub>			
Qs	Stored charge	I <sub>T</sub> = 1000A, tp = 1000us,T <sub>j</sub> = 125°C, dl/dt =10A/μs,		-	1000	μC
I <sub>RR</sub>	Reverse recovery current			-	85	А
١L	Latching current	$T_j = 25^{\circ}C,$		-	1	А
I <sub>H</sub>	Holding current	T <sub>j</sub> = 25°C,		-	200	mA

# GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V <sub>GT</sub>	Gate trigger voltage	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	3	V
$V_{GD}$	Gate non-trigger voltage	At 40% V <sub>DRM</sub> , T <sub>case</sub> = 125°C	0.3	V
I <sub>GT</sub>	Gate trigger current	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	300	mA
I <sub>GD</sub>	Gate non-trigger current	At 40% V <sub>DRM,</sub> T <sub>case</sub> = 125°C	20	mA

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## CURVES

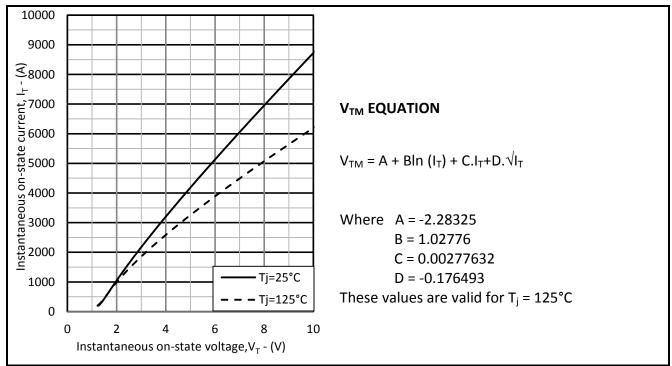


Fig.2 Maximum & minimum on-state characteristics

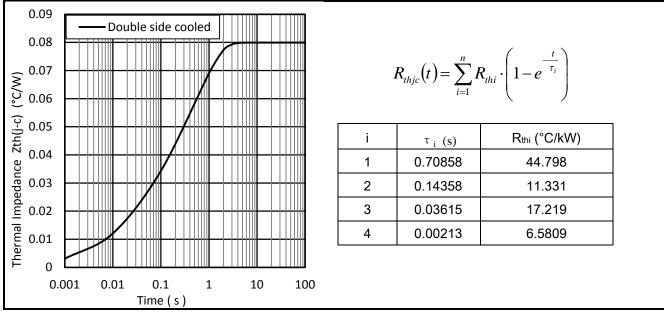
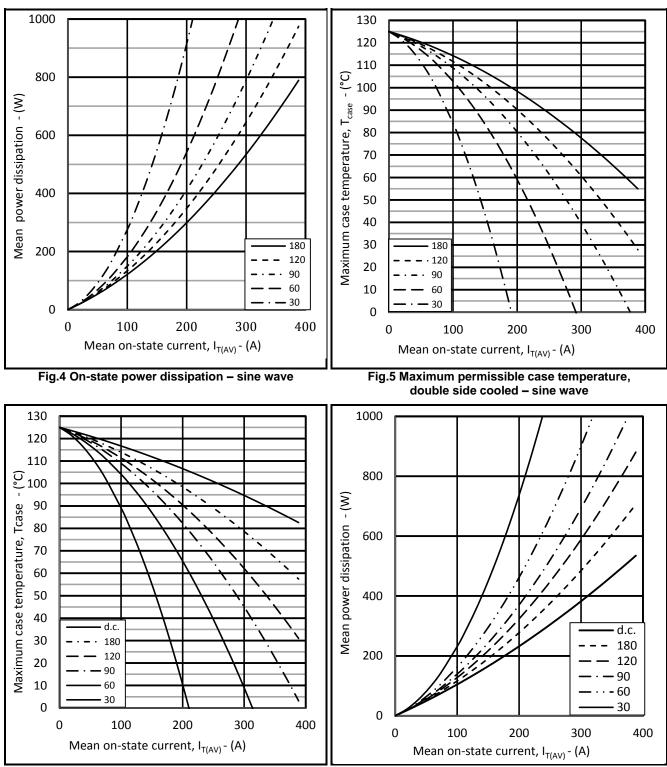
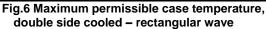


Fig.3 Maximum (limit) transient thermal impedance - junction to case (°C/W)



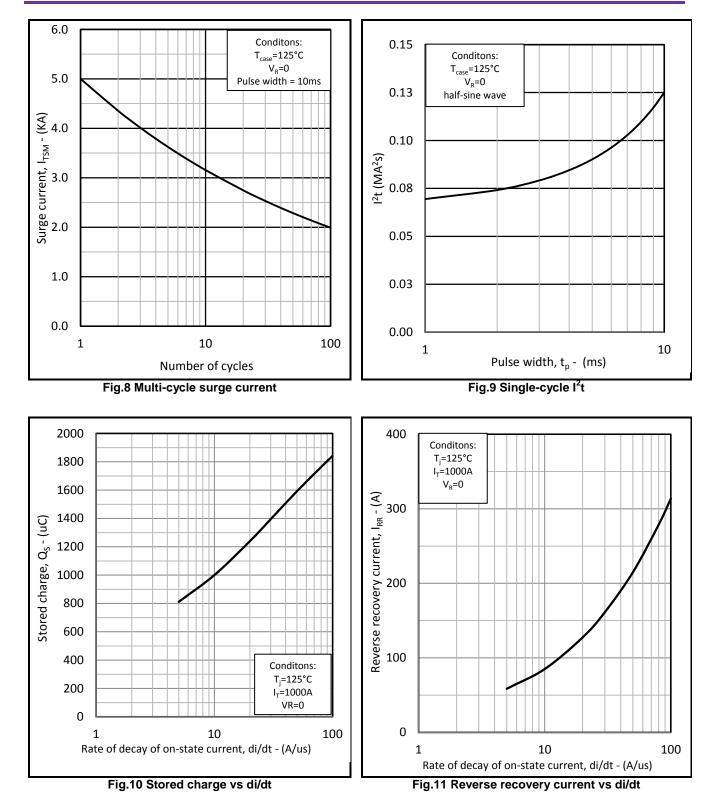


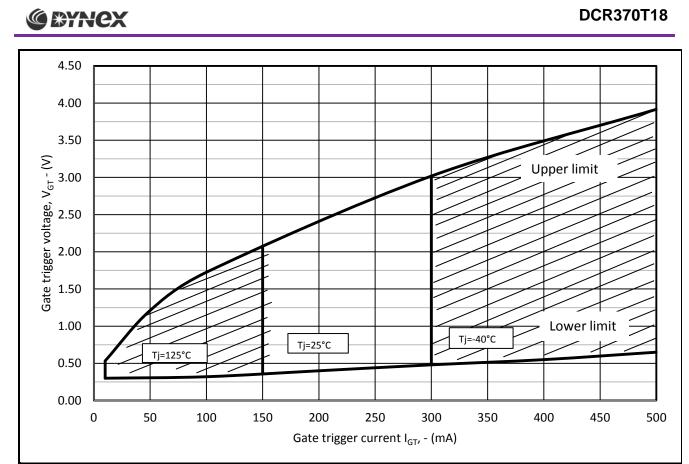




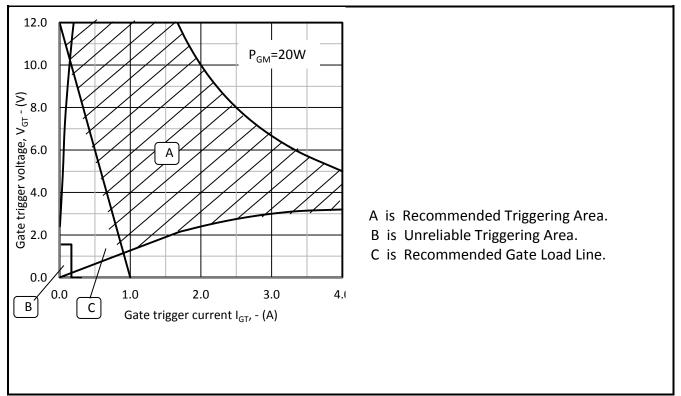


### DCR370T18





#### Fig.12 Gate characteristics



#### Fig.13 Gate characteristics



### PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

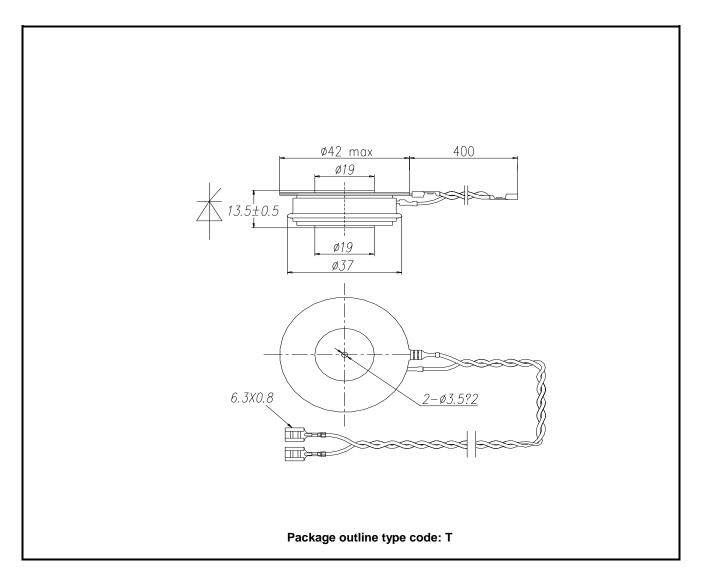


Fig.14 Package outline



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